

RT3K66M

Composite Transistor
For high speed switching
Silicon N-channel MOSFET

DESCRIPTION

RT3K66M is a composite transistor built with two INK0012AX chips in SC-88 package.

FEATURE

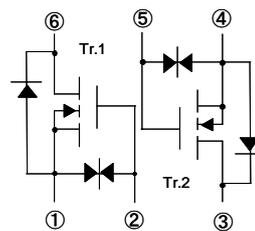
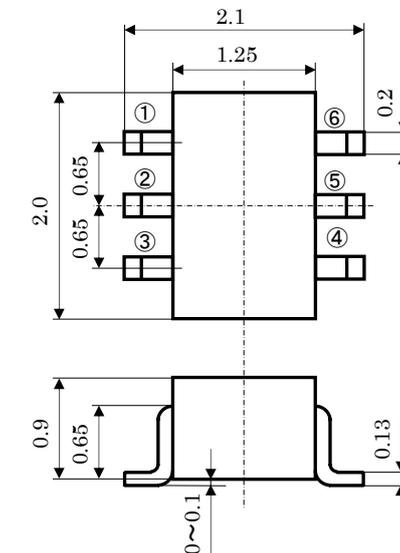
- Input impedance is high, and not necessary to consider a drive electric current.
- V_{th} is low, and drive by low voltage is possible. $V_{th}=1.0\sim 2.0V$
- Low on Resistance.
 $R_{bs(on)}=1.7\Omega$ (TYP) @ $I_D=100mA$, $V_{GS}=4.0V$
 $R_{bs(on)}=1.0\Omega$ (TYP) @ $I_D=100mA$, $V_{GS}=10V$
- High speed switching.
- Small package for easy mounting.

APPLICATION

High speed switching , Analog switching

OUTLINE DRAWING

Unit:mm



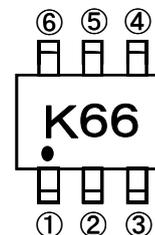
TERMINAL CONNECTOR
①:SOURCE1
②:GATE1
③:DRAIN2
④:SOURCE2
⑤:GATE2
⑥:DRAIN1

JEITA:SC-88

MAXIMUM RATING ($T_a=25^\circ C$)

SYMBOL	PARAMETER	RATING	UNIT
V_{DSS}	Drain-source voltage	30	V
V_{GSS}	Gate-source voltage	± 20	V
I_D	Drain current	200	mA
P_D	Total power dissipation ($T_a=25^\circ C$)	150	mW
T_{ch}	Channel temperature	+150	$^\circ C$
T_{stg}	Range of Storage temperature	-55~+150	$^\circ C$

MARKING



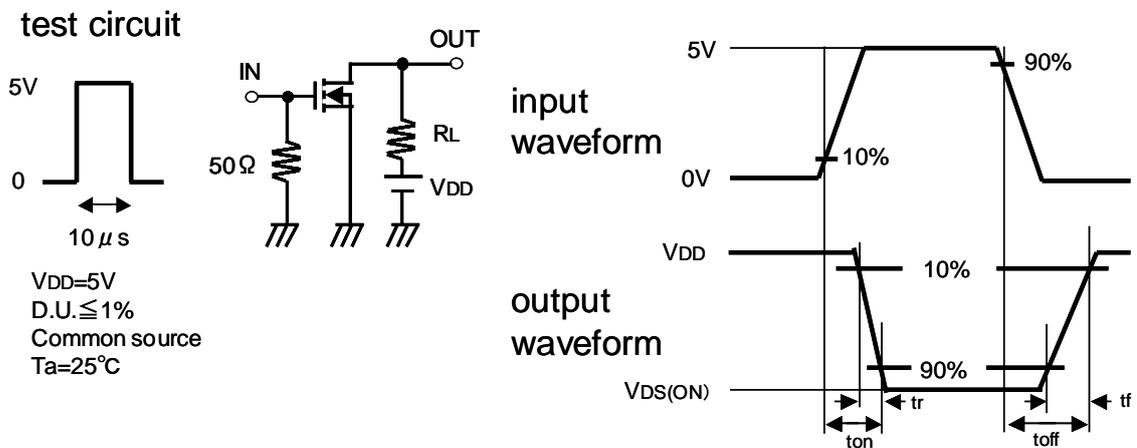
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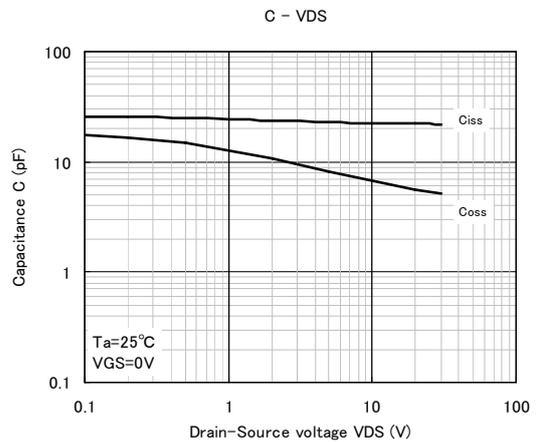
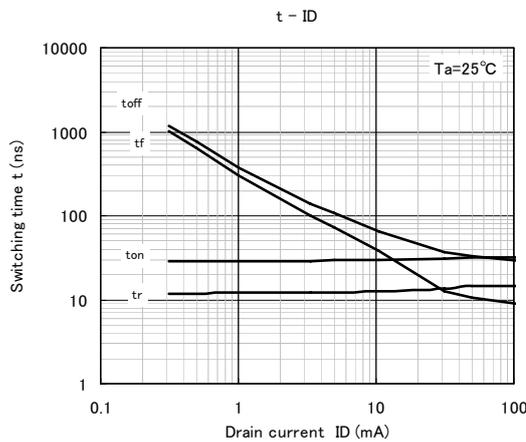
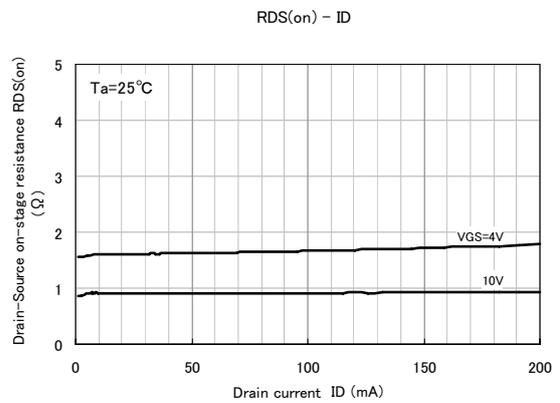
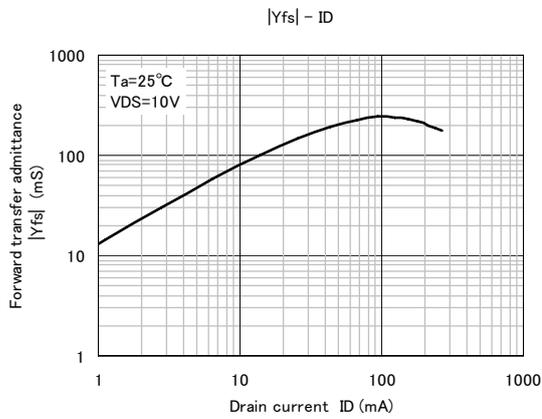
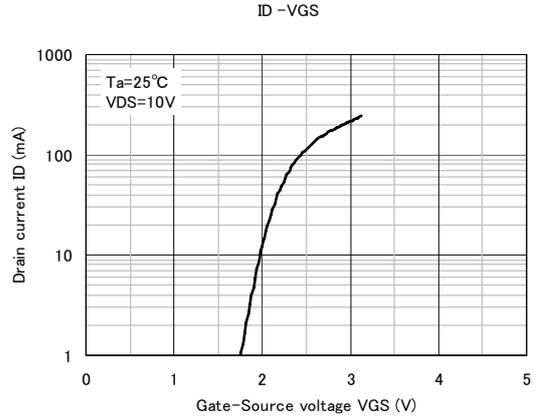
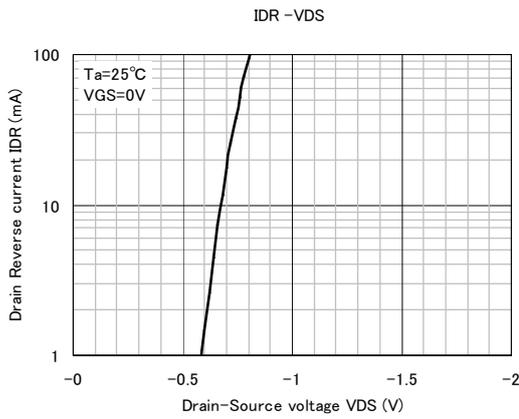
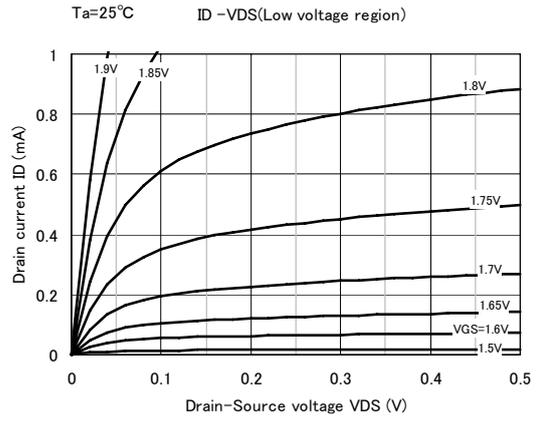
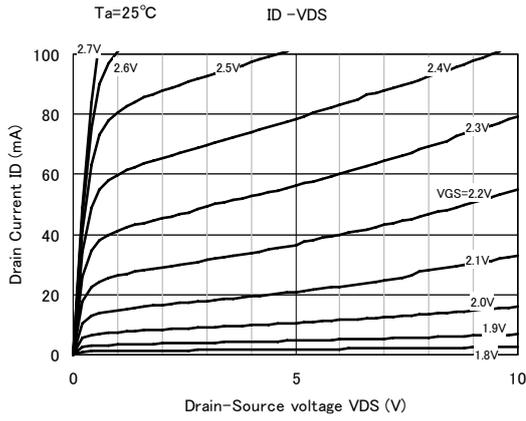
ELECTRICAL CHARACTERISTICS (Ta=25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D=100\mu A, V_{GS}=0V$	30	-	-	V
I_{GSS}	Gate-source leak current	$V_{GS}=\pm 15V, V_{DS}=0V$	-	-	± 1.0	μA
I_{DSS}	Zero gate voltage drain current	$V_{DS}=30V, V_{GS}=0V$	-	-	1.0	μA
V_{th}	Gate threshold voltage	$I_D=250\mu A, V_{DS}=V_{GS}$	1.0	-	2.0	V
$ Y_{fs} $	Forward transfer admittance	$V_{DS}=10V, I_D=100mA$	-	245	-	mS
$R_{DS(on)}$	Static drain-source on-state resistance	$I_D=100mA, V_{GS}=4.0V$	-	1.7	-	Ω
		$I_D=100mA, V_{GS}=10.0V$	-	1.0	-	
C_{iss}	Input capacitance	$V_{DS}=10V, V_{GS}=0V, f=1MHz$	-	23	-	pF
C_{oss}	Output capacitance		-	7.0	-	pF
t_{ON}	Switching time	$V_{DD}=5V, I_D=10mA$ $V_{GS}=0\sim 5V$	-	30	-	ns
t_{OFF}			-	66	-	

Switching time test condition



TYPICAL CHARACTERISTICS





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